

WN3S80170CWT

Dual power Schottky diode

Rev.01 - 20 November 2024

Product data sheet

1. General description

Dual common cathode power Schottky diode designed for high frequency switched mode power supplies in a TO247 plastic package



2. Features and benefits

- High junction temperature up to 175°C
- · Low forward voltage drop, negligible switching losses
- High efficiency

3. Applications

- DC to DC converters
- Freewheeling diode
- OR-ing diode
- · Switched mode power supply rectifier

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Notes		Values	;	Unit
Absolute	maximum rating						
V_{RRM}	repetitive peak reverse voltage				170		V
$I_{F(AV)}$	average forward current	δ = 0.5 ; square-wave pulse; per diode; Fig. 1; Fig. 2; Fig. 3			40		A
I _{O(AV)}	average output current	δ = 0.5 ; square-wave pulse; both diodes conducting			80		A
Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit
Static ch	aracteristics						
V _F	forward voltage	$I_F = 40 \text{ A}; T_j = 25 \text{ °C}; \text{ per diode}; Fig. 6$		-	0.80	0.84	V
I _R	reverse current	V_R = 170 V; T _j = 25 °C; per diode; <u>Fig. 7</u>		-	0.3	20	μA

5. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	A1	anode 1		
2	К	cathode		
3	A2	anode 2		K sym125
mb	К	mounting base; connected to cathode	TO247	

6. Ordering information

Table 3. Ordering information								
Type number	Package name	Orderable part number	Packing method	Small packing quantity	Package version	Package issue date		
WN3S80170CWT	TO247	WN3S80170CWTQ	Tube	30	TO247P	09-Mar-2023		

7. Marking

Table 4.	Marking	codes
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Type number	Marking codes
WN3S80170CWT	WN3S80
	170CWT

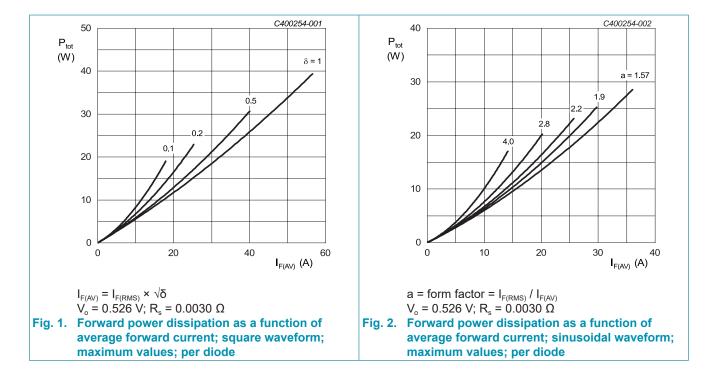
8. Limiting values

Table 5. Limiting values

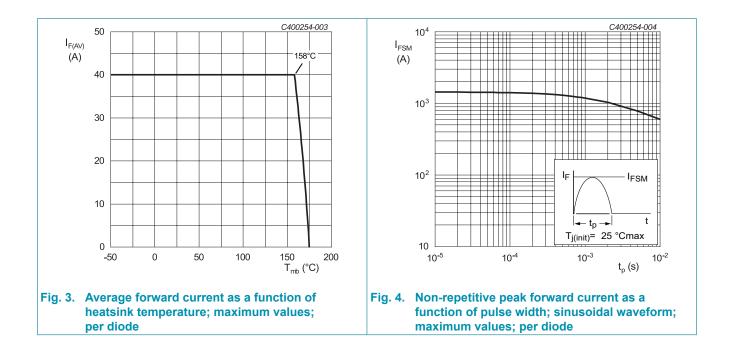
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Notes	Values	Unit
V_{RRM}	repetitive peak reverse voltage			170	V
V_{RWM}	crest working reverse voltage			170	V
V _R	reverse voltage	DC		170	V
I _{F(AV)}	average forward current	δ = 0.5 ; square-wave pulse; per diode; Fig. 1; Fig. 2; Fig. 3		40	А
I _{O(AV)}	average output current	δ = 0.5 ; square-wave pulse; both diodes conducting		80	A
I _{FSM}	non-repetitive peak forward current	t_p = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; per diode; Fig. 4		600	A
		t_p = 8.3 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; per diode		660	A
T _{stg}	storage temperature			-40 to 175	°C
T _j	junction temperature		[1]	-40 to 175	°C

[1] The heat generated must be less than the thermal conductivity from Junction to Ambient: $dP_{tot}/dT_j < 1/R_{th(j-a)}$



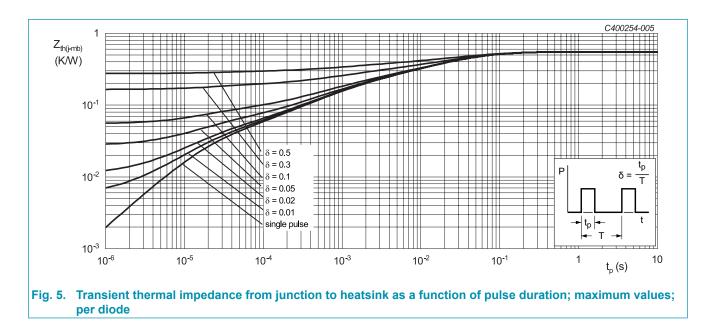
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9. Thermal characteristics

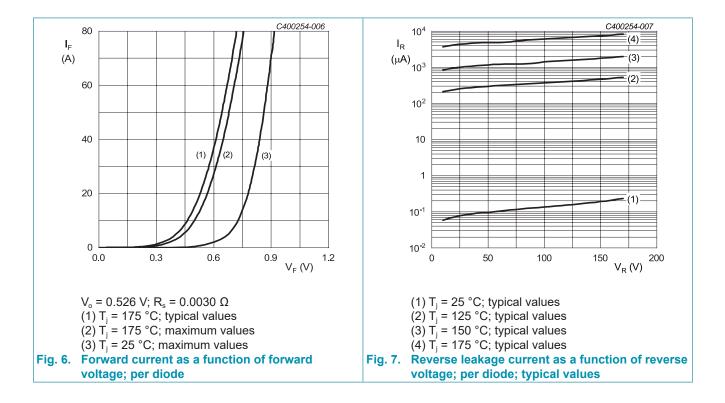
Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit
R _{th(j-h)}	thermal resistance from junction to	with heatsink compound; per diode; Fig. <u>5</u>		-	-	0.55	K/W
	heatsink	with heatsink compound; both diodes conducting		-	-	0.26	K/W
R _{th(j-a)}	thermal resistance from junction to ambient free air	in free air		-	40	-	K/W

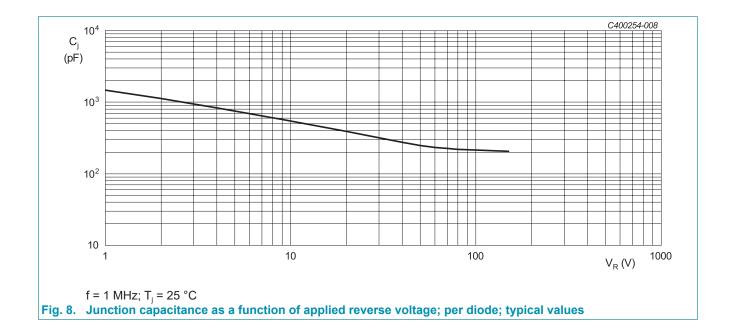


10. Characteristics

Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit
Static ch	aracteristics						
V _F	forward voltage	$I_{F} = 40 \text{ A}; T_{j} = 25 \text{ °C}; \text{ per diode}; Fig. 6$		-	0.80	0.84	V
		$I_{F} = 40 \text{ A}; T_{j} = 125 \text{ °C}; \text{ per diode}$		-	0.67	-	V
		$I_{F} = 40 \text{ A}; T_{j} = 175 \text{ °C}; \text{ per diode}; Fig. 6$		-	0.61	0.65	V
I _R	reverse current	V _R = 170 V; T _j = 25 °C; per diode; <u>Fig. 7</u>		-	0.3	20	μA
		V _R = 170 V; T _j = 125 °C; per diode; <u>Fig. 7</u>		-	0.5	-	mA

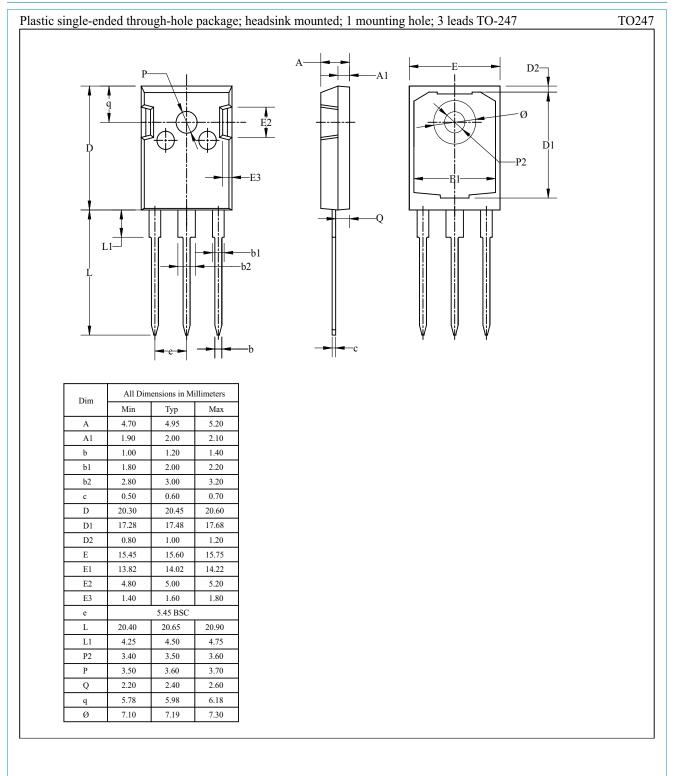


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11. Package outline



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Dual power Schottky diode

12. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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- [2] The term 'short data sheet' is explained in section "Definitions".
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <u>http://www.ween-semi.com</u>.

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